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Application Number	To be assigned	90/52561-4
Filing Date	Herewith	8/5/90
First Named Inventor	Henry W. White et al.	
Art Unit	To be assigned	
Examiner Name	To be assigned	
Attorney Docket Number	MOXT-002-US	

[illegible]

Examiner's Initials*	Cite No. <sup>1</sup>	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T <sup>8</sup>
		Country Code <sup>2</sup> – Number <sup>3</sup> – Kind Code <sup>6</sup> (if known)				
/A.R./		EP 0591 607 A2	04/13/1994	Mitsubishi Denki Kabushiki Kaisha		
/A.R./		EP 1 054 082 A1	11/22/2000	Stanley Electric Co., Ltd.		
/A.R./		EP 1 081 256 A2	03/07/2001	Stanley Electric Co., Ltd.		
Examiner Signature	/Angel Roman/			Date Considered	06/27/2010	

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10525611 - GAU: 2812

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<b>Application Number</b>	To be assigned	<b>10/525611</b>
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<b>Examiner Name</b>	To be assigned	
<b>Attorney Docket Number</b>	MOXT-002-US	

## OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS

Examiner Initials*		T <sup>2</sup>
/A.R./	Ko, H.J. et al. "Photoluminescence properties of ZnO epilayers grown on CaF <sub>2</sub> (111) by plasma assisted molecular beam epitaxy." Applied Physics Letters, Volume 76, Number 14, April 3, 2000, pp. 1905-1907.	
	Ryu, Y.R. et al. "Properties of arsenic-doped p-type ZnO grown by hybrid beam deposition." Applied Physics Letters, Volume 83, Number 1, July 7, 2003, pp. 87-89.	
	Ryu, Y.R. et al. "Synthesis of p-type ZnO films." Journal of Crystal Growth, 216 (2000), pp. 330-334.	
	Kumano, H. et al. "Luminescence properties of ZnO films grown on GaAs substrates by molecular-beam epitaxy excited by electron-cyclotron resonance oxygen plasma." Journal of Crystal Growth 214/215 (2000), pp. 280-283.	
	López, J. García et al. "Role of the oxygen plasma during in situ growth of YBa <sub>2</sub> Cu <sub>3</sub> O <sub>6+x</sub> thin films by pulsed laser deposition." Physica C 307 (1998), pp. 298-306.	
	Tsurumi, Takaaki et al. "Electric Properties of Zinc Oxide Epitaxial Films Grown by Ion-Beam Sputtering with Oxygen-Radical Irradiation." Japanese Journal of Applied Physics, Vol. 38 (1999), pp. 3682-3688.	
	Ryu, Y.R. et al. "Fabrication of homostructural ZnO p-n junctions." Journal of Crystal Growth 219 (2000), pp.419-422.	

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